

OKI electronic components

OCS40

Optical PNPN Switches with OFF Function

GENERAL DESCRIPTION

The OCS40 adds an OFF function to the standard optical PNPN switch to provide an optically controlled ON-OFF function. In addition to standard latch functions, the OCS40 also offers a pulse-drive-controlled ON-OFF capability.

FEATURES

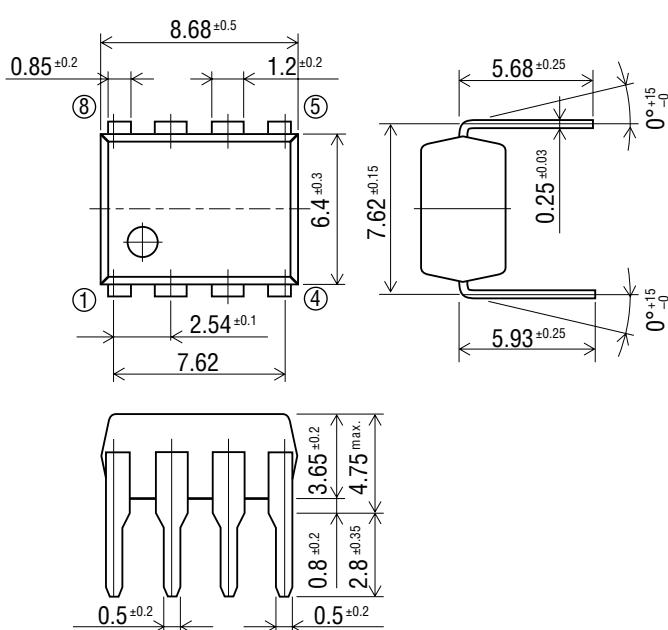
- ON-OFF control using pulse
- Low drive current (I_{GON} , I_{GOFF} : 10 mA Max.)
- High blocking voltage (V_{BO} , V_{BD} : 350 V Min.)
- Total I/O isolation

APPLICATIONS

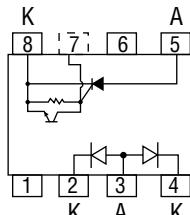
- Electronic automatic exchange
- Key telephone system
- Home electronics
- Measuring instrument
- Substitute for latching relay
- Optically coupled circuits

PIN CONFIGURATION

(Unit: mm)



• Pin Connection Diagram



- 1: NC (No connection)
- 2: OFF Cathode (LED)
- 3: ON, OFF Anode (LED)
- 4: ON Cathode (LED)
- 5: PNPN Anode
- 6: NC (No connection)
- 7: PIN cut
- 8: PNPN Cathode

ABSOLUTE MAXIMUM RATINGS

| Parameter | | Symbol | Test Condition | Rating | Unit |
|-----------------------|-----------------------------|---------------------|----------------|-------------|------|
| Input (LED) | Forward Current | I _G | Ta=25°C | 60 | mA |
| | Reverse Voltage | V _{RL} | | 5 | V |
| Output (PNPN) | Forward Blocking Current | V _{BO} | Ta=25°C | 350 | V |
| | Reverse Voltage | V _{BD} | | 350 | V |
| | Continuous ON-State Current | I _F | | 100 | mA |
| | Surge ON-State Current * | I _{SUG} | | 1.4 | A |
| | Isolation Voltage | V _{in-out} | | 1500 | V |
| Operating Temperature | | T _{opr} | — | -20 to +70 | °C |
| Storage Temperature | | T _{stg} | — | -55 to +125 | °C |

* A single 1 ms pulse

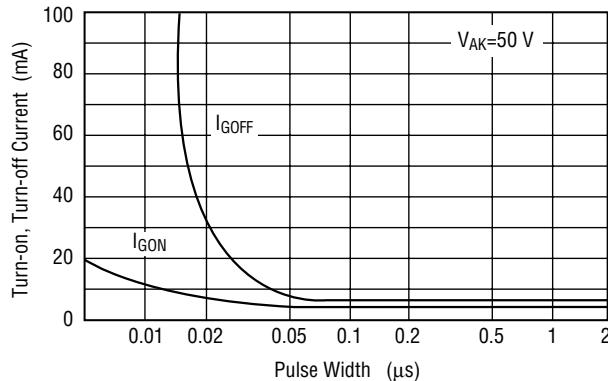
ELECTRICAL CHARACTERISTICS

(Ambient Temperature Ta=25°C)

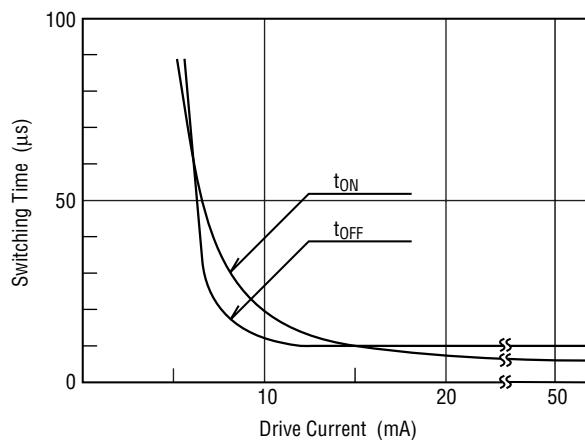
| Parameter | | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-------------------------|-------------------|-------------------|---|------|------|------|---------|
| Input Characteristics | Forward Voltage | V _{FL} | I _G =40 mA | — | — | 1.4 | V |
| | Reverse Current | I _{RL} | V _{RL} =5 V | — | — | 5 | μA |
| Output Characteristics | OFF-State Current | I _{BO} | V _{BD} =320 V | — | — | 5 | μA |
| | Reverse Current | I _{BD} | V _{BD} =320 V | — | — | 5 | μA |
| | ON-State Voltage | V _F | I _F =20 mA, I _G =40 mA | — | — | 1.0 | V |
| | dV/dt Capability | dV/dt | — | 80 | — | — | V/0.1μs |
| | | | I _{GOFF} =0.25 mA | 210 | — | — | |
| Coupled Characteristics | Holding Current | I _H | ON to OFF | — | — | 1.3 | mA |
| | Turn on Current | I _{GON} | V _{AK} =50 V | — | — | 10 | mA |
| | | | V _{AK} =50 V, I _{GOFF} =0.35 mA | — | — | 10 | |
| | Turn off Current | I _{GOFF} | I _F =100 mA | — | — | 10 | mA |

TYPICAL CHARACTERISTICS

- Turn-on, Turn-off Current vs. Pulse Width ($T_a=25^\circ C$)

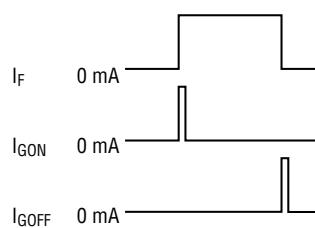


- Switching Time vs. Drive Current ($T_a=25^\circ C$)



- Drive Example

i) Pulse Drive

ii) Offset Drive
(High dV/dt capability is obtained)